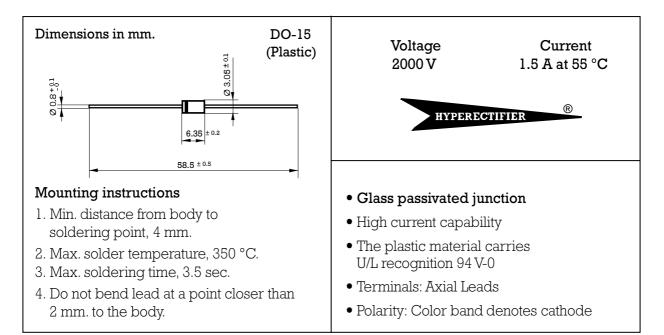


## 1.5 Amp. Glass Passivated Fast Diode



## Maximum Ratings, according to IEC publication No. 134

		<b>RGP</b> 15-20
V <sub>RRM</sub>	Peak recurrent reverse voltage	2000 V
I <sub>F(AV)</sub>	Forward current at Tamb = 55 °C	1.5 A
I <sub>FRM</sub>	Recurrent peak forward current	6 A
$I_{\rm FSM}$	8.3 ms. peak forward surge current	20 A
t <sub>rr</sub>	$ \begin{array}{l} \text{Max. reverse recovery} \\ \text{time from} \end{array} \begin{array}{l} I_{\text{F}} = 0.5 \text{ A} \\ I_{\text{R}} = 1 \text{ A} \\ I_{\text{RR}} = 0.25 \text{ A} \end{array} $	300 ns
C <sub>j</sub>	Typical Junction Capacitance at 1 MHz and reverse voltage of $4V_{\mbox{\tiny DC}}$	5 pF
Tj	Operating temperature range	– 65 to + 175 °C
T <sub>stg</sub>	Storage temperature range	– 65 to + 175 °C

## Electrical Characteristics at Tamb = 25 °C

V <sub>F</sub>	Max. forward voltage drop at $I_F = 1.5 P$	3 V
I <sub>R</sub>	Max. reverse current at $V_{RRM}$ at 25 °C at 150 °C	5 µ A 50 µ A
R <sub>thj-a</sub>	Max. thermal resistance (I = 10 mm.)	30 °C/W

**RGP15-20** 



